# PNP EPITAXIAL SILICON TRANSISTOR

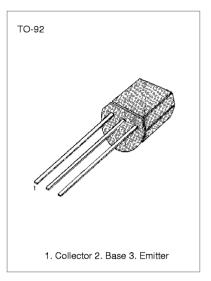
## **SWITCHING AND AMPLIFIER**

• HIGH VOLTAGE: BC556, V<sub>CEO</sub>= -65V • LOW NOISE: BC559, BC560

## • Complement to BC546 ... BC 550

## ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C)

Characteristic	Symbol	Rating	Unit
Collector-Base Capacitance : BC556 : BC557/560	V <sub>CBO</sub>	-80 -50	V V
: BC558/559 Collector-Emitter Voltage : BC556 : BC557/560 : BC558/559	V <sub>CEO</sub>	-30 -65 -45 -30	V V V
Emitter-Base Voltage Collector Current (DC) Collector Dissipation Junction Temperature Storage Temperature	V <sub>EBO</sub> I <sub>C</sub> P <sub>C</sub> T <sub>J</sub> T <sub>STG</sub>	-30 -5 -100 500 150 -65 ~ 150	∨ mA mW °C °C



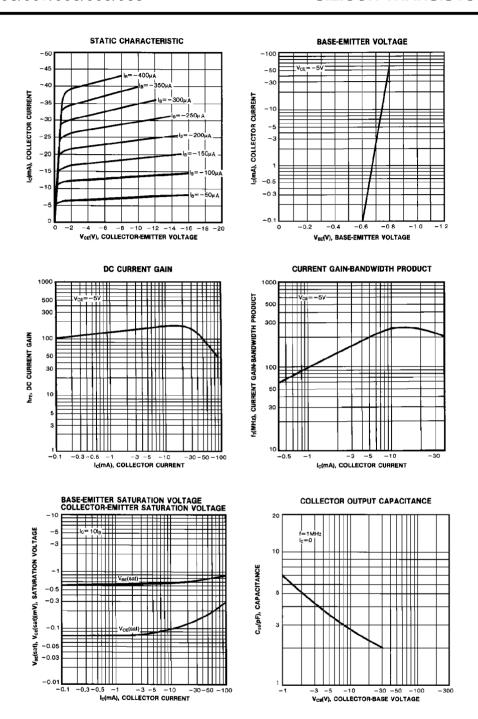
# **ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C)**

Char	racteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
Collector Cut-off C	urrent	l <sub>CBO</sub>	V <sub>CB</sub> = -30V, I <sub>E</sub> =0	110		-15	n <b>A</b>
DC Current Gain		h <sub>FE</sub>	V <sub>CE</sub> = -5V, I <sub>C</sub> =2mA	110		800	١,,
Collector Emitter S	saturation Voltage	V <sub>CE</sub> (sat)	$I_{C}=-10\text{mA}, I_{B}=-0.5\text{mA}$		-90	-300	mV
0 " . 5 0 .		\/ (an)	$I_{C}=-100\text{mA}, I_{B}=-5\text{mA}$		-250	-650	mV
Collector Base Sat	turation Voltage	V <sub>BE</sub> (on)	l <sub>C</sub> = -10mA, l <sub>B</sub> = -0.5mA		-700		mV
			l <sub>C</sub> = -100mA, l <sub>B</sub> = -5mA		-900		mV
Base Emitter On V	oltage	V <sub>BE</sub> (on)	$V_{CE}$ = -5V, $I_{C}$ = -2mA	-600	-660	-750	mV
			$V_{CE} = -5V, I_{C} = -10mA$			-800	mV
Current Gain Band	lwidth Product	f <sub>T</sub>	$V_{CE} = -5V$ , $I_{C} = -10mA$		150		MHz
Collector Base Ca	pacitance	Ссво	V <sub>CB</sub> = -10V, f=1MHz			6	рF
Noise Figure	: BC556/557/558	NF	V <sub>CE</sub> = -5V, I <sub>C</sub> = -200μA		2	10	dΒ
<b>3</b>	: BC559/560		f=1KHz, R <sub>G</sub> =2KΩ		l 1	4	dB
	: BC559	NF	V <sub>CE</sub> = -5V, I <sub>C</sub> = -200μA		1.2	4	dB
	: BC559 : BC560		R <sub>G</sub> =2KΩ		1.2	2	dB
			f=30~15000MHz				

# h<sub>FE</sub> CLASSIFICATION

Classification	Α	В	С
h <sub>FE</sub>	110-220	200-450	420-800







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E²CMOS™ PowerTrench™

FACT<sup>TM</sup> QS<sup>TM</sup>

FACT Quiet Series  $^{\text{TM}}$  Quiet Series  $^{\text{TM}}$  SuperSOT  $^{\text{TM}}$ -3 FAST  $^{\text{TM}}$  SuperSOT  $^{\text{TM}}$ -6 GTO  $^{\text{TM}}$  SuperSOT  $^{\text{TM}}$ -8 HiSeC  $^{\text{TM}}$ 

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